

SHINDENGEN

Schottky Rectifiers (SBD)

Dual

S1ZAS4

40V 1.2A

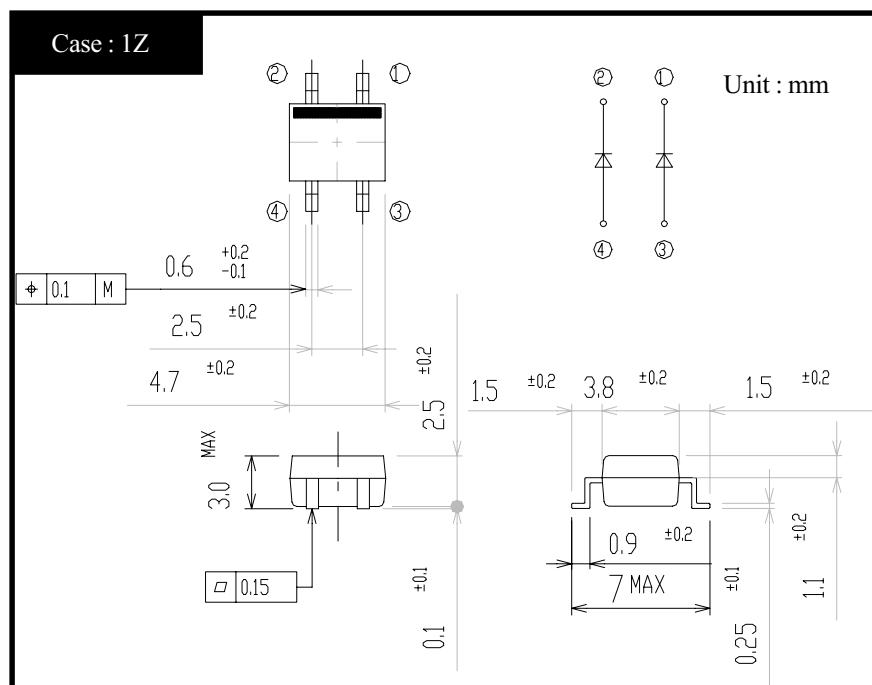
FEATURES

- SMT
- T_j 150°C
- P_{RRSM} avalanche guaranteed
- Array

APPLICATION

- Switching power supply
- DC/DC converter
- Home Appliances, Office Equipment
- Telecommunication

OUTLINE DIMENSIONS



RATINGS

● Absolute Maximum Ratings (If not specified $T_f=25^\circ\text{C}$)

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T_{stg}		-40~150	°C
Operating Junction Temperature	T_j		150	°C
Maximum Reverse Voltage	V_{RM}		40	V
Repetitive Peak Surge Reverse Voltage	V_{RRSM}	Pulse width 0.5ms, duty 1/40	45	V
Average Rectified Forward Current	I_o	50Hz sine wave, R-load, On alumina substrate, 1 element operation, $T_a=49^\circ\text{C}$	1.2	A
		50Hz sine wave, R-load, On alumina substrate, 2 element operation, $T_a=45^\circ\text{C}$	0.9*	
		50Hz sine wave, R-load, On glass-epoxy substrate, 1 element operation, $T_a=47^\circ\text{C}$	1.0	
		50Hz sine wave, R-load, On glass-epoxy substrate, 2 element operation, $T_a=43^\circ\text{C}$	0.72*	
Peak Surge Forward Current	I_{FSM}	50Hz sine wave, Non-repetitive 1 cycle peak value, $T_j=125^\circ\text{C}$	40	A
Repetitive Peak Surge Reverse Power	P_{RRSM}	Pulse width 10 μs , Rating of per diode, $T_j=25^\circ\text{C}$	160	W

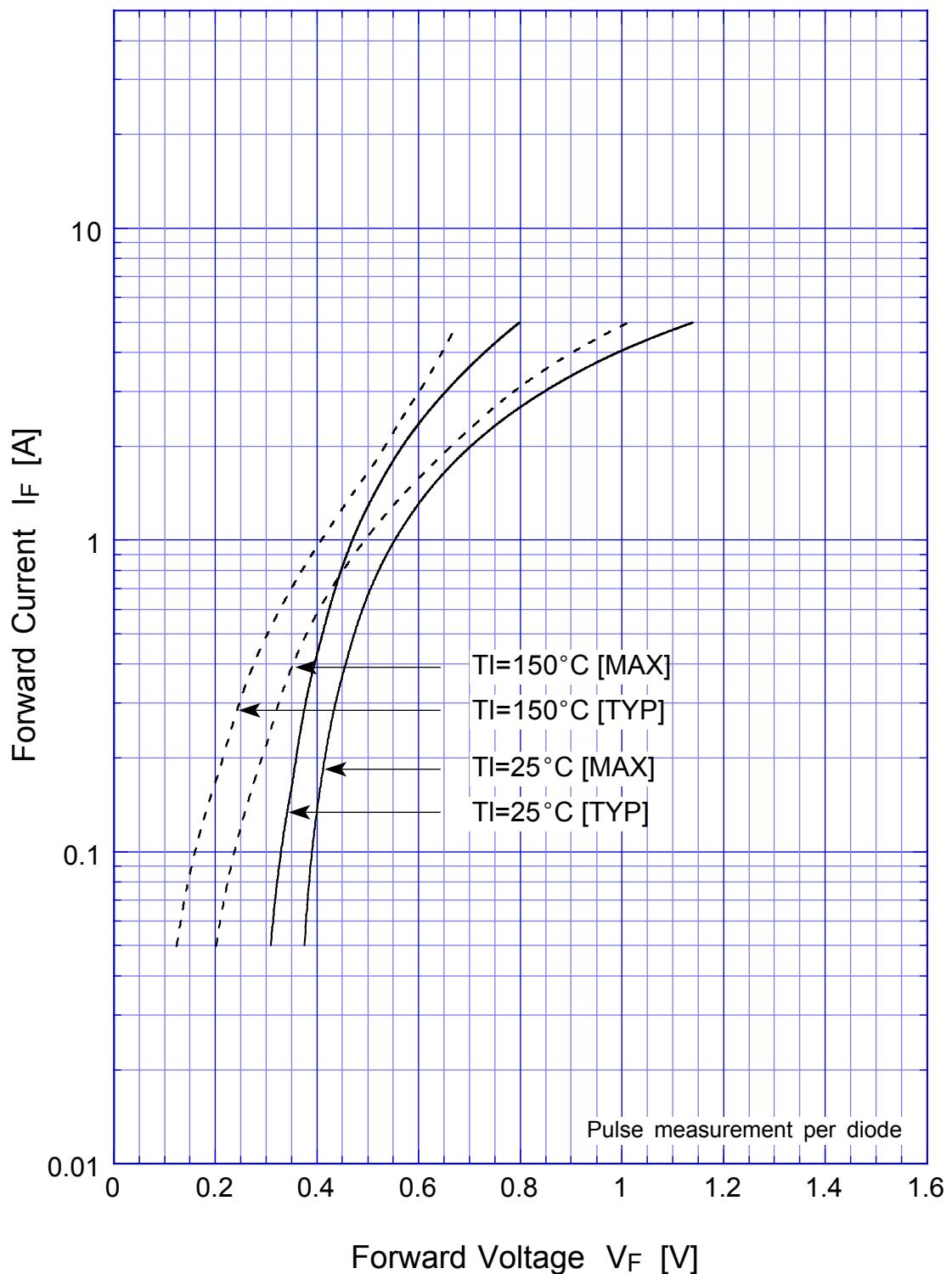
● Electrical Characteristics (If not specified $T_f=25^\circ\text{C}$)

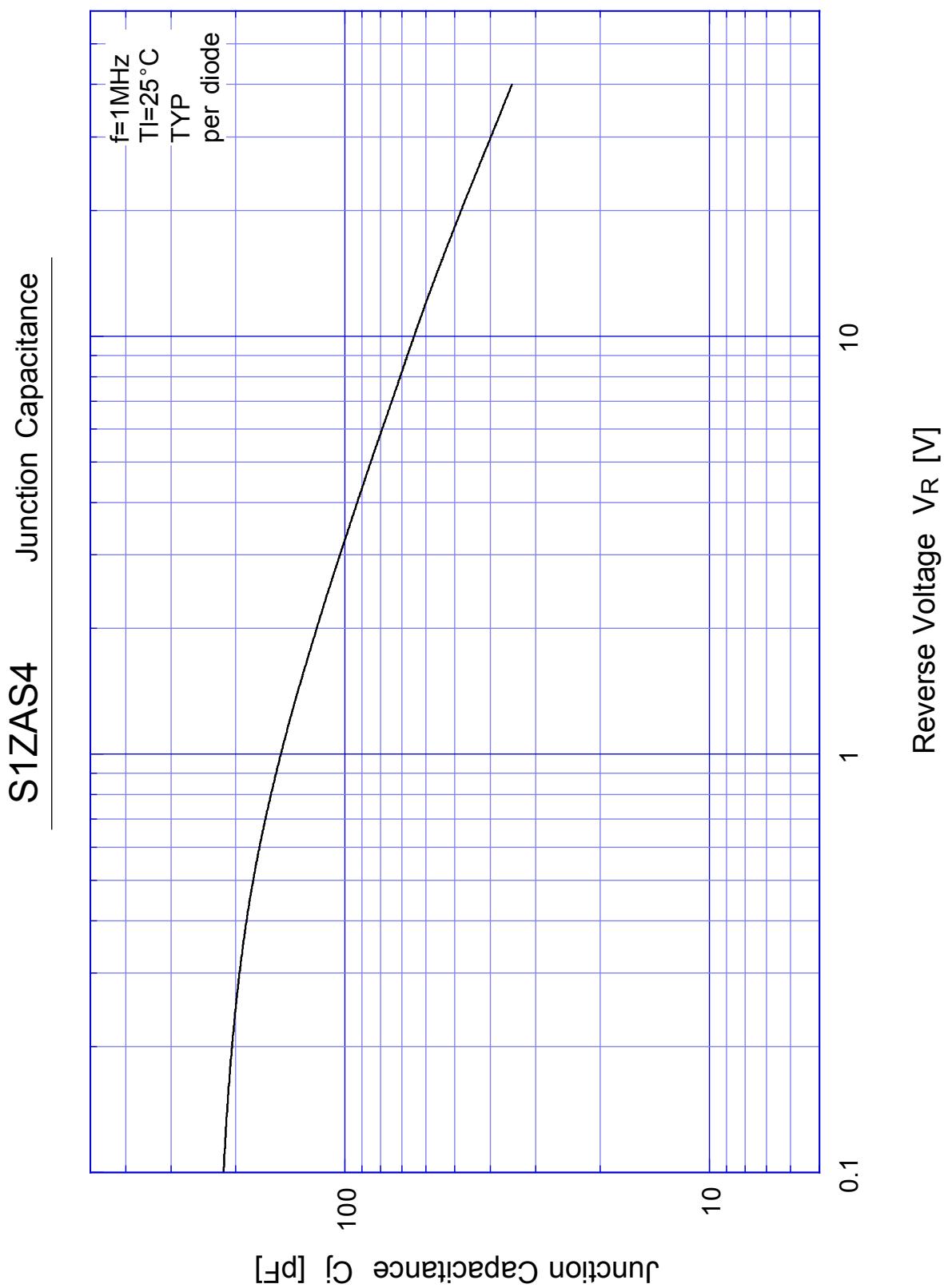
Item	Symbol	Conditions	Ratings	Unit
Forward Voltage	V_F	$I_F=1\text{A}$, Pulse measurement, Rating of per diode	Max.0.55	V
Reverse Current	I_R	$V_R=V_{RM}$, Pulse measurement, Rating of per diode	Max.1	mA
Junction Capacitance	C_j	$f=1\text{MHz}$, $V_R=10\text{V}$, Rating of per diode	Typ.65	pF
Thermal Resistance	θ_{jl}	junction to lead	Max.25	°C/W
	junction to ambient, On alumina substrate, 1 element operation	Max.93		
	junction to ambient, On alumina substrate, 2 element operation	Max.140*		
	junction to ambient, On glass-epoxy substrate, 1 element operation	Max.120		
junction to ambient, On glass-epoxy substrate, 2 element operation				Max.186*

* : Rating of per diode

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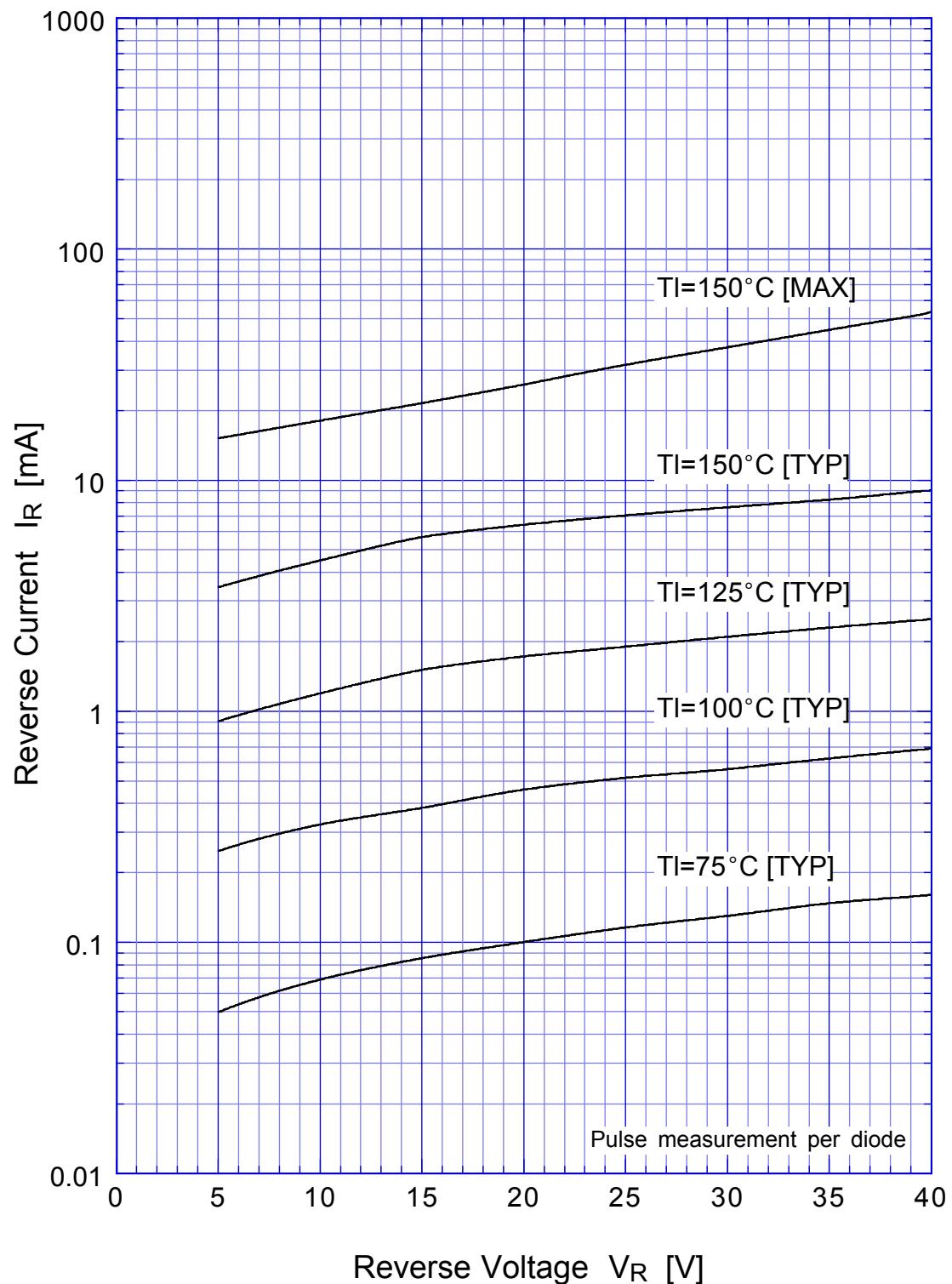
Forward Voltage





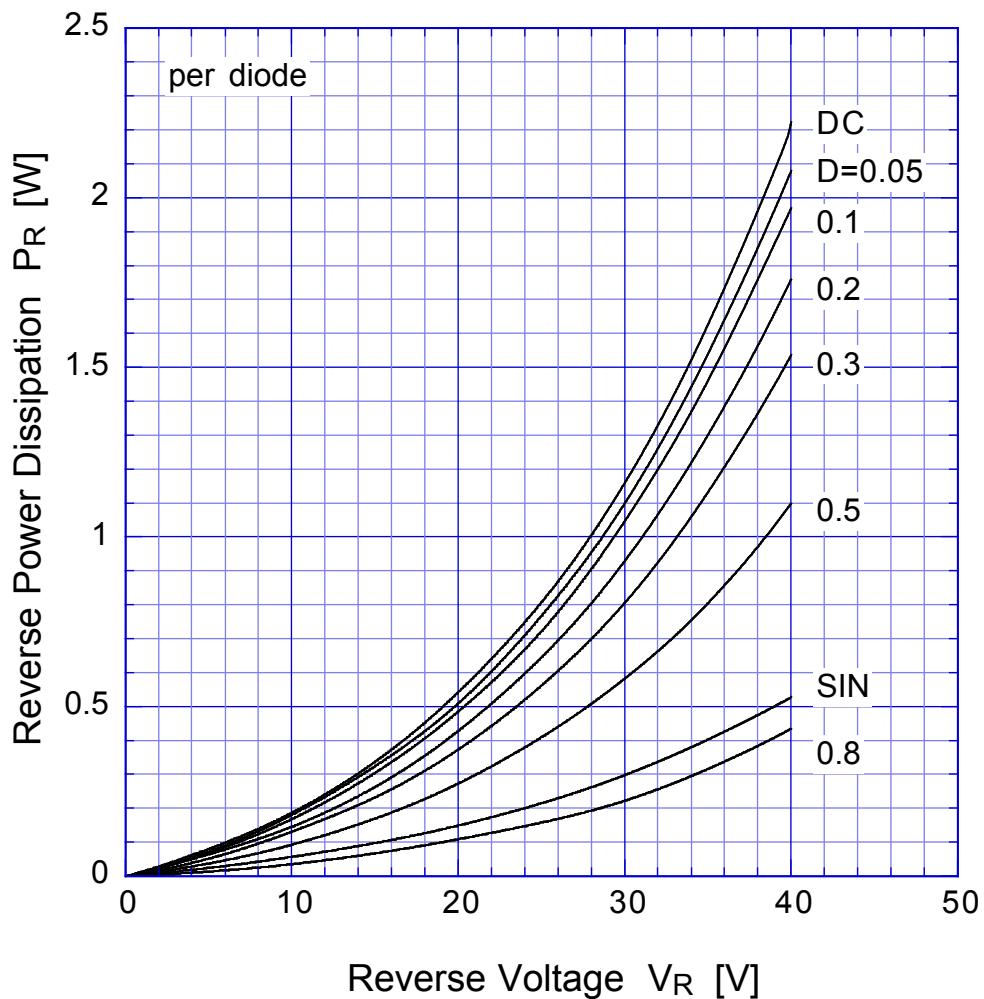
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Reverse Current

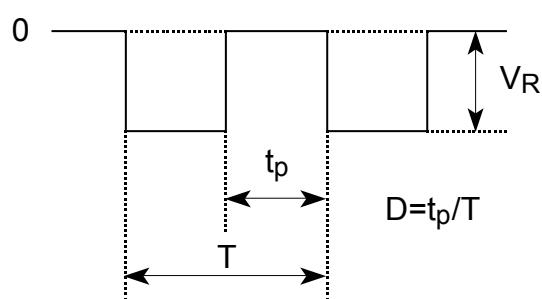


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Reverse Power Dissipation

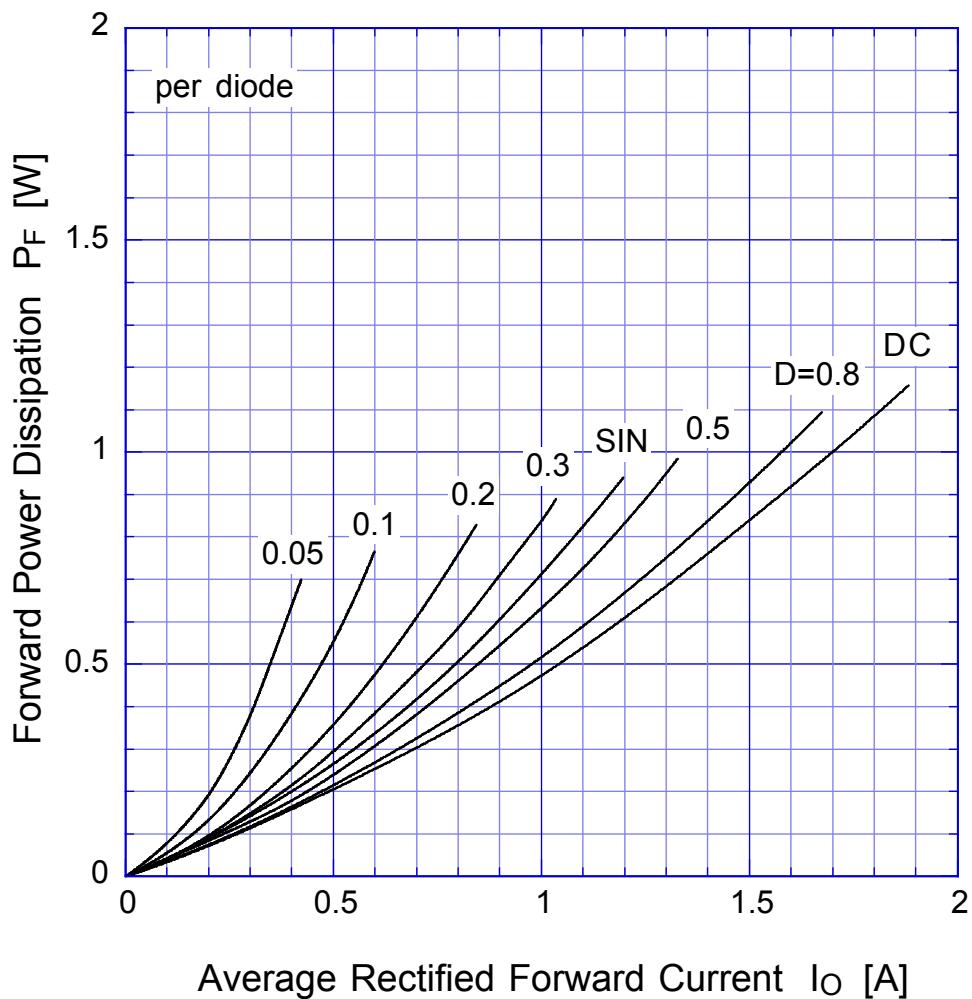


$T_j = 150^\circ\text{C}$

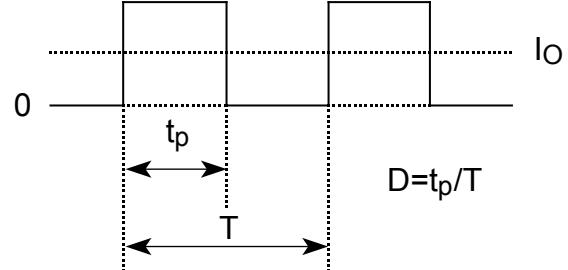


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Forward Power Dissipation

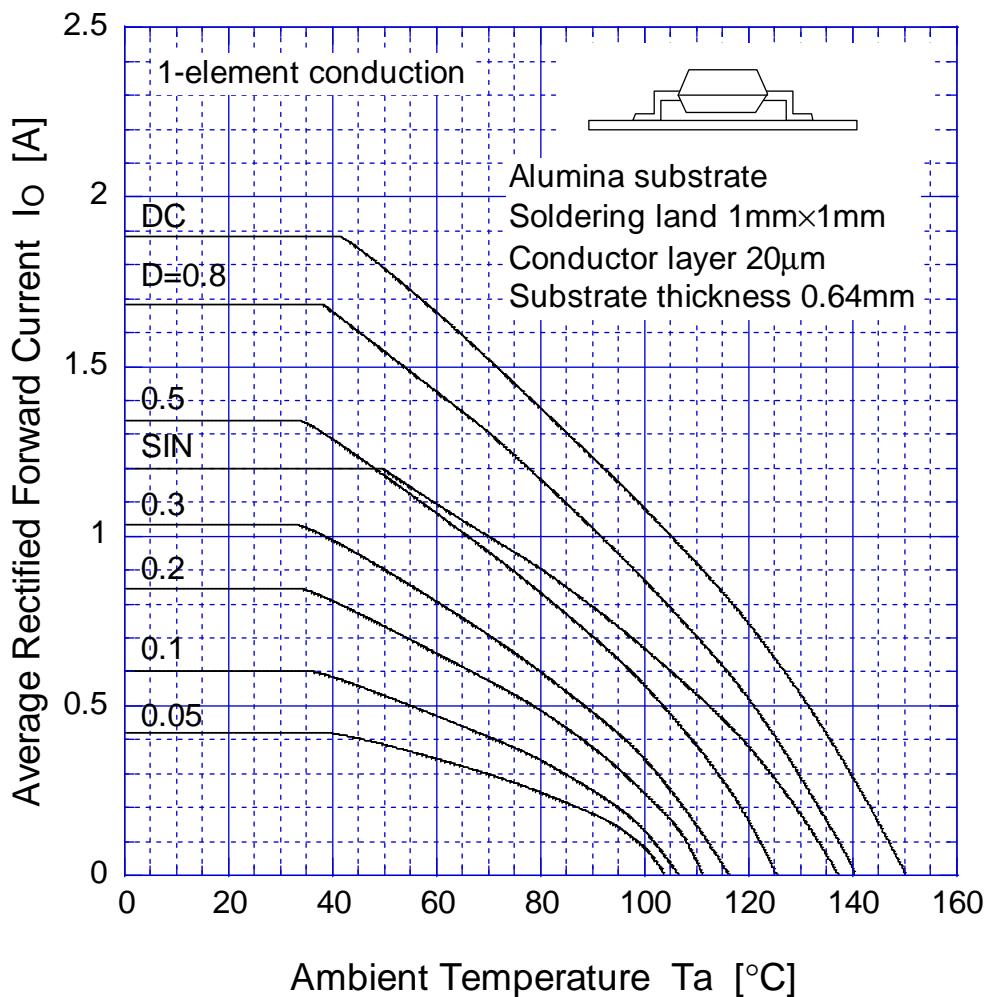


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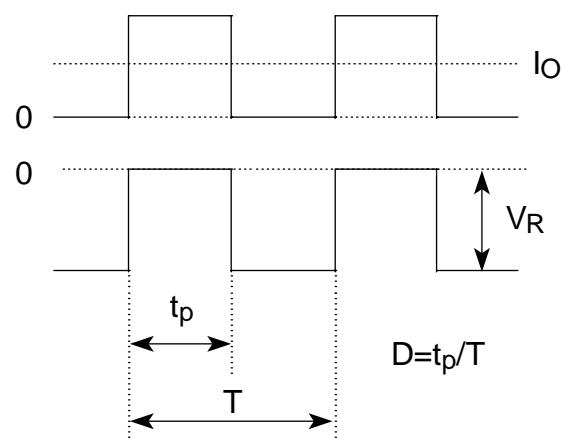


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Derating Curve

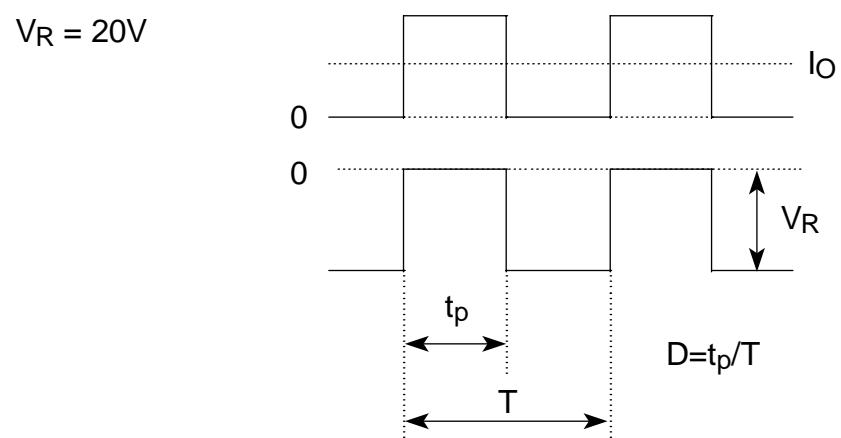
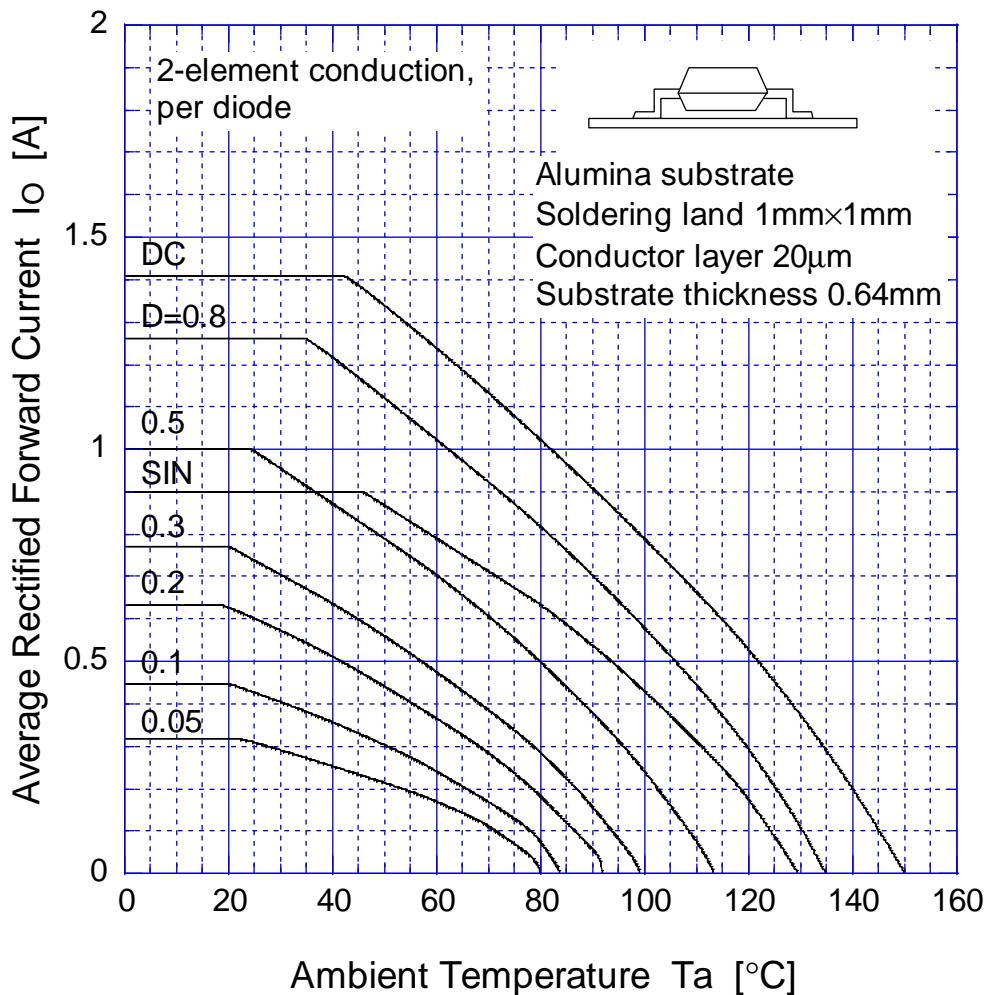


$V_R = 20V$



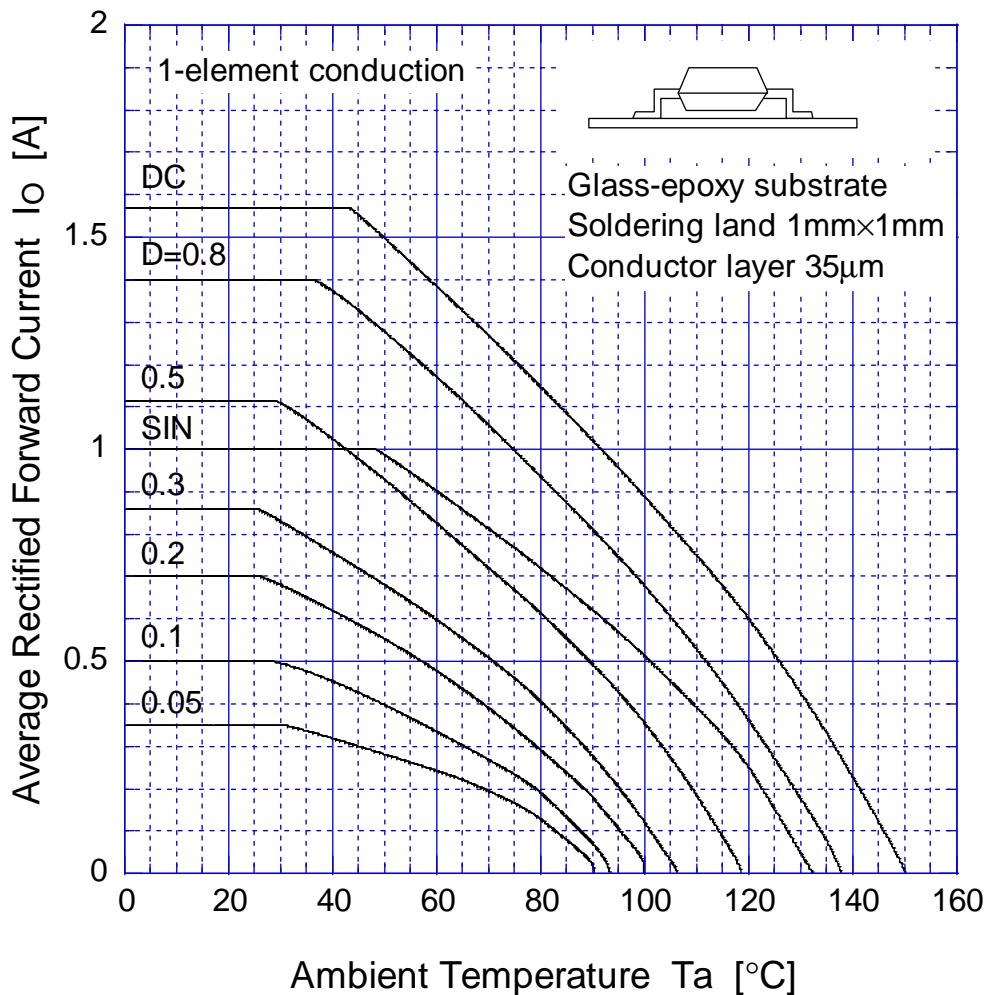
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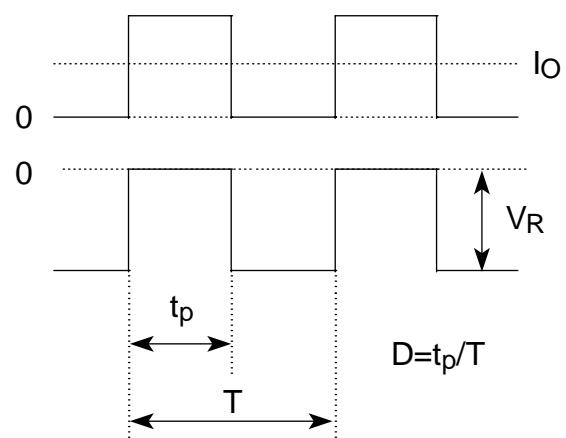


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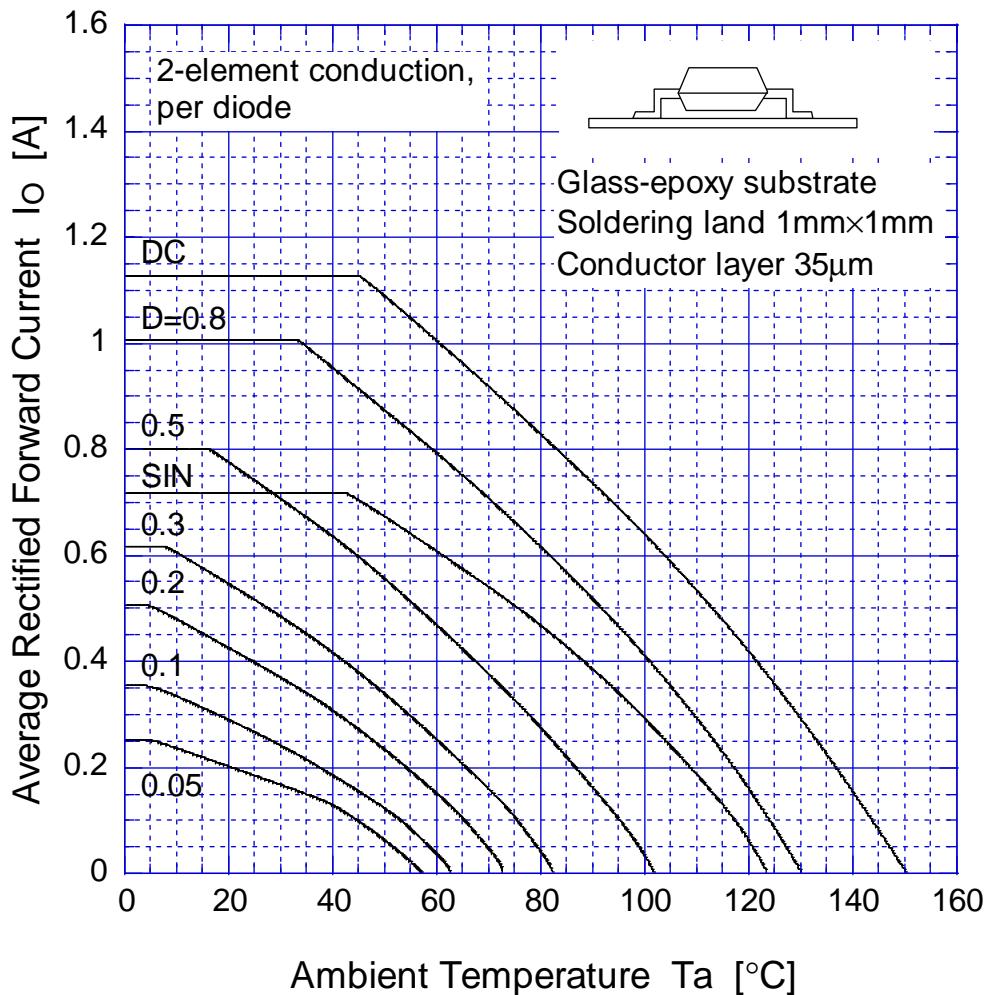


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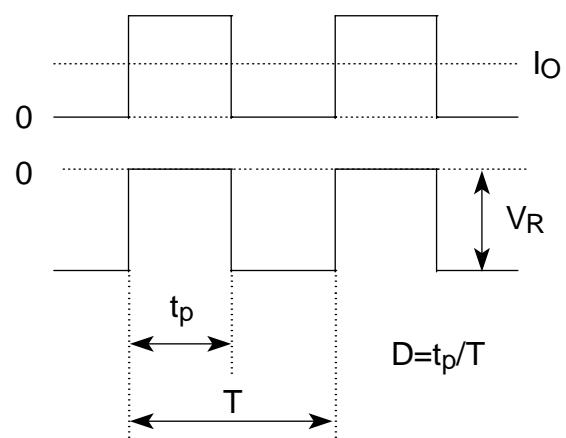


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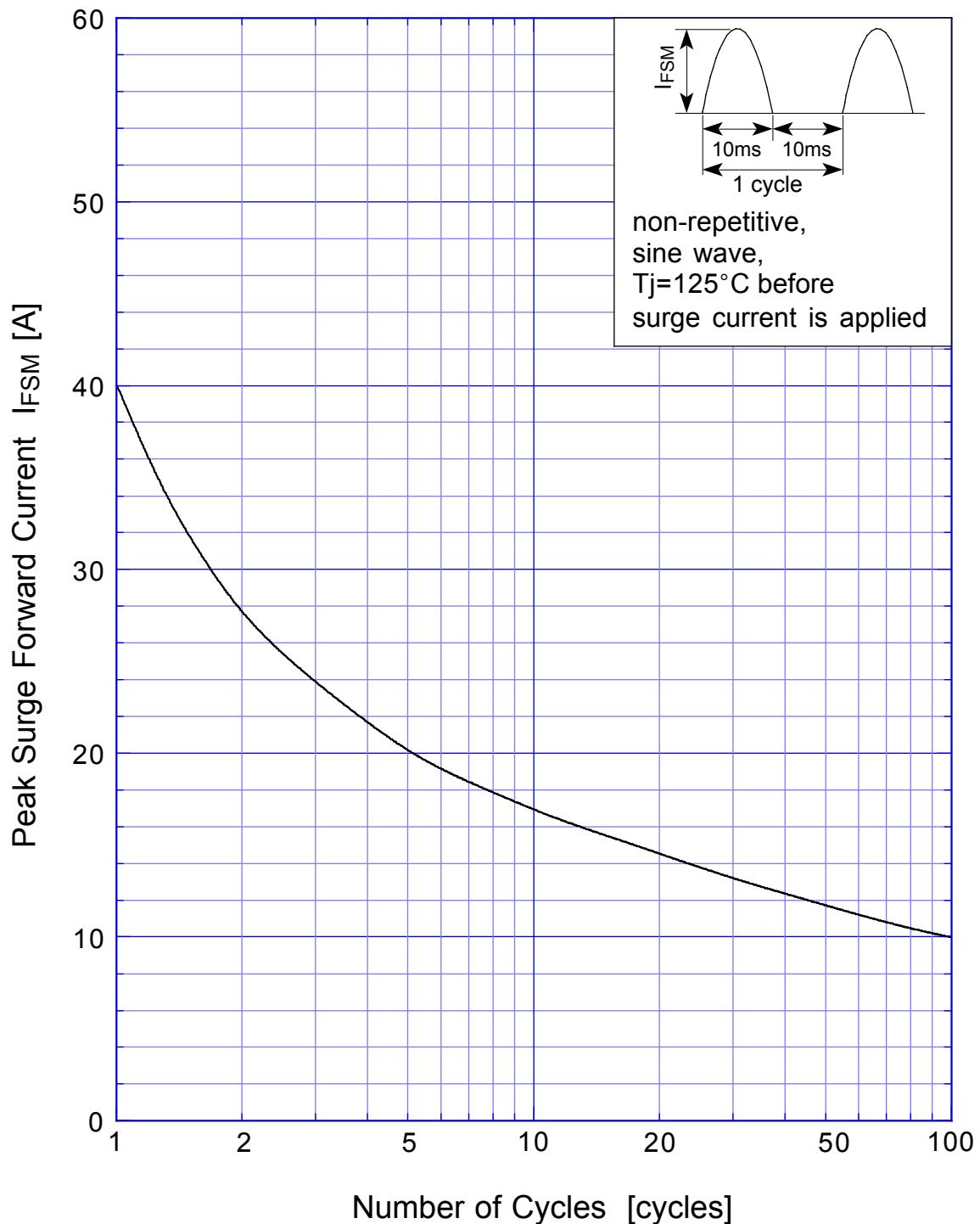


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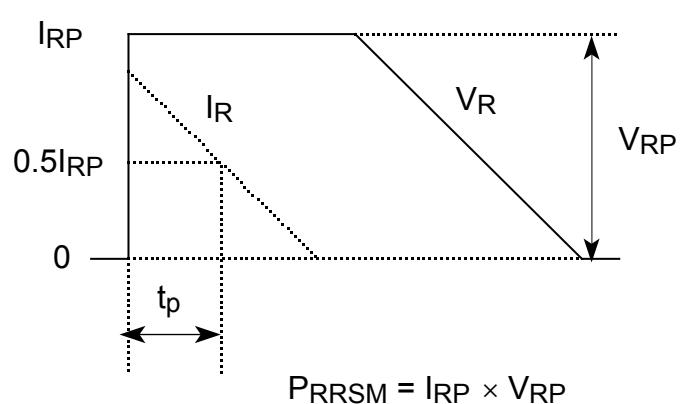
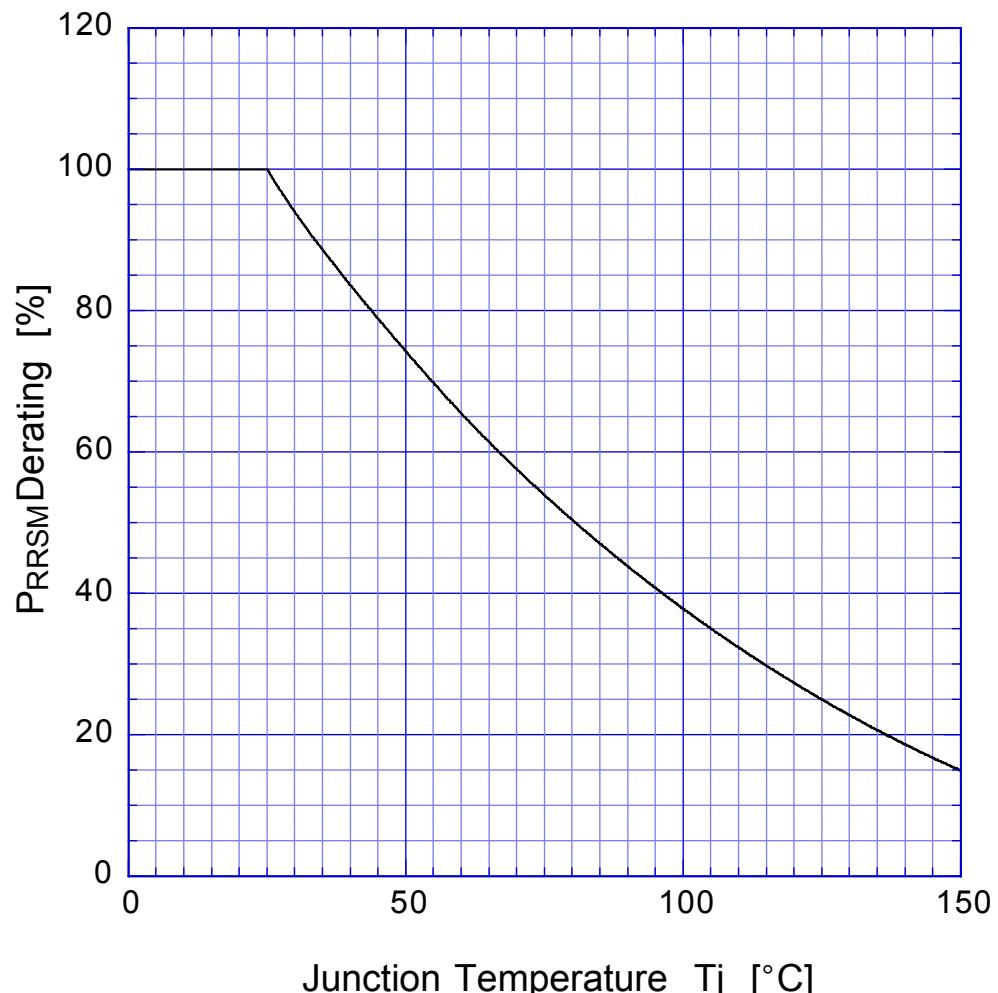


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Peak Surge Forward Capability



SBD Repetitive Surge Reverse Power Derating Curve



SBD Repetitive Surge Reverse Power Capability

